**MTIL113** 

**STYLE 1 PLASTIC** 

STANDARD THRU HOLE



# 6-Pin DIP Optoisolators Darlington Output

The MTIL113 device consists of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon photodarlington detector.

This device is designed for use in applications requiring high collector output currents at lower input currents.

- Higher Sensitivity to Low Input Drive Current
- Meets or Exceeds All JEDEC Registered Specifications

### Applications

- Low Power Logic Circuits
- · Interfacing and coupling systems of different potentials and impedances
- Telecommunications Equipment
- Portable Electronics
- Solid State Relays

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

| Symbol | Value                | Unit                                                        |
|--------|----------------------|-------------------------------------------------------------|
|        |                      |                                                             |
| VR     | 3                    | Volts                                                       |
| lF     | 60                   | mA                                                          |
| PD     | 100<br>1.41          | mW<br>mW/°C                                                 |
|        | V <sub>R</sub><br>IF | V <sub>R</sub> 3<br>I <sub>F</sub> 60<br>P <sub>D</sub> 100 |

## SCHEMATIC 1 1 2 2 4 PIN 1. LED ANODE 2. LED CATHODE 3. N.C. 4. EMITTER 5. COLLECTOR

6. BASE

#### OUTPUT DETECTOR

| Collector–Emitter Voltage                                               | VCEO | 30          | Volts       |
|-------------------------------------------------------------------------|------|-------------|-------------|
| Emitter–Collector Voltage                                               | VECO | 5           | Volts       |
| Collector-Base Voltage                                                  | VCBO | 30          | Volts       |
| Collector Current — Continuous                                          | ΙC   | 125         | mA          |
| Detector Power Dissipation @ T <sub>A</sub> = 25°C<br>Derate above 25°C | PD   | 150<br>1.76 | mW<br>mW/°C |

#### TOTAL DEVICE

| Isolation Surge Voltage <sup>(2)</sup><br>(Peak ac Voltage, 60 Hz, 1 sec Duration) | VISO             | 7500        | Vac(pk)     |
|------------------------------------------------------------------------------------|------------------|-------------|-------------|
| Total Device Power Dissipation @ T <sub>A</sub> = 25°C<br>Derate above 25°C        | PD               | 250<br>2.94 | mW<br>mW/°C |
| Ambient Operating Temperature Range <sup>(3)</sup>                                 | TA               | -55 to +100 | °C          |
| Storage Temperature Range <sup>(3)</sup>                                           | T <sub>stg</sub> | -55 to +150 | °C          |
| Soldering Temperature (10 sec, 1/16" from case)                                    | тլ               | 260         | °C          |

1. All Motorola 6-Pin devices exceed JEDEC specification and are 7500 Vac(pk).

2. Isolation surge voltage is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

3. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.



## www.DaMShBa1413.om

ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)<sup>(1)</sup>

| Characteristic                                                                                      | Symbol                              | Min      | <b>Typ</b> (1)   | Max  | Unit    |
|-----------------------------------------------------------------------------------------------------|-------------------------------------|----------|------------------|------|---------|
| NPUT LED                                                                                            | •                                   | •        | 1                |      |         |
| Reverse Leakage Current ( $V_R = 3 V$ , $R_L = 1 M$ ohms)                                           | IR                                  | —        | 0.05             | 100  | μA      |
| Forward Voltage (I <sub>F</sub> = 10 mA)                                                            | VF                                  | —        | 1.34             | 1.5  | Volts   |
| Capacitance (V <sub>R</sub> = 0 V, f = 1 MHz)                                                       | С                                   | —        | 1.8              | —    | pF      |
| <b>DUTPUT DETECTOR</b> (T <sub>A</sub> = $25^{\circ}$ C and I <sub>F</sub> = 0, unless otherwise no | oted)                               |          |                  |      |         |
| Collector–Emitter Dark Current<br>(V <sub>CE</sub> = 10 V, Base Open)                               | <sup>I</sup> CEO                    | -        | —                | 100  | nA      |
| Collector–Base Breakdown Voltage $(I_C = 100 \ \mu\text{A}, I_E = 0)$                               | V <sub>(BR)</sub> CBO               | 30       | —                | —    | Volts   |
| Collector–Emitter Breakdown Voltage $(I_C = 100 \ \mu\text{A}, I_B = 0)$                            | V(BR)CEO                            | 30       | —                | —    | Volts   |
| Emitter–Collector Breakdown Voltage (IE = 100 $\mu$ A, IB = 0)                                      | V(BR)ECO                            | 5        | —                | —    | Volts   |
| DC Current Gain<br>( $V_{CE} = 5 V$ , I <sub>C</sub> = 500 $\mu$ A)                                 | hFE                                 | -        | 16K              | —    | —       |
| <b>COUPLED</b> (T <sub>A</sub> = 25°C unless otherwise noted)                                       | •                                   |          |                  |      | •       |
| Collector Output Current $(3)$<br>(V <sub>CE</sub> = 1 V, I <sub>F</sub> = 10 mA)                   | I <sub>C</sub> (CTR) <sup>(2)</sup> | 30 (300) | —                | —    | mA (%)  |
| Isolation Surge Voltage <sup>(4,5)</sup><br>(60 Hz ac Peak, 1 Second)                               | VISO                                | 7500     | —                | _    | Vac(pk) |
| Isolation Resistance <sup>(4)</sup><br>(V = 500 V)                                                  | RISO                                | -        | 10 <sup>11</sup> | —    | Ohms    |
| Collector–Emitter Saturation Voltage(3)<br>( $I_C = 2 \text{ mA}, I_F = 8 \text{ mA}$ )             | V <sub>CE(sat)</sub>                | -        | —                | 1.25 | Volts   |
| Isolation Capacitance(4)<br>(V = 0 V, f = 1 MHz)                                                    | C <sub>ISO</sub>                    | -        | 0.2              | _    | pF      |
| Turn–On Time(6)<br>(I <sub>C</sub> = 50 mA, I <sub>F</sub> = 200 mA, V <sub>CC</sub> = 10 V)        | ton                                 | -        | 0.6              | 5    | μs      |
| Turn–Off Time(6)<br>(I <sub>C</sub> = 50 mA, I <sub>F</sub> = 200 mA, V <sub>CC</sub> = 10 V)       | toff                                | -        | 45               | 100  | μs      |

1. Always design to the specified minimum/maximum electrical limits (where applicable).

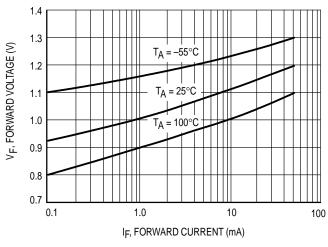
2. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .

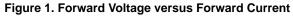
3. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2%.

4. For this test, Pins 1 and 2 are common and Pins 4, 5 and 6 are common.

5. Isolation Surge Voltage,  $V_{\mbox{\scriptsize ISO}},$  is an internal device dielectric breakdown rating.

6. For test circuit setup and waveforms, refer to Figures 8 and 9.





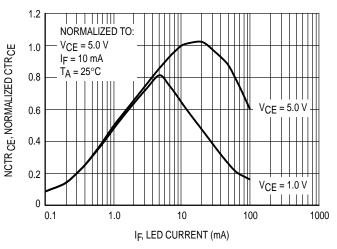
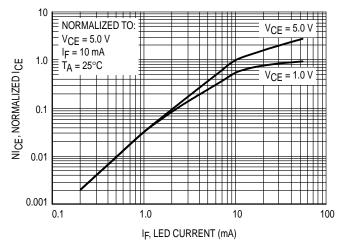


Figure 2. Normalized Non–Saturated and Saturated CTRce versus LED Current



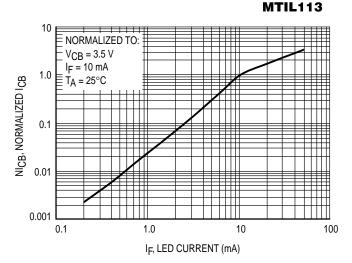


Figure 3. Normalized Non–Saturated and Saturated Collector–Emitter Current versus LED Current

Figure 4. Normalized Collector–Base Photocurrent versus LED Current

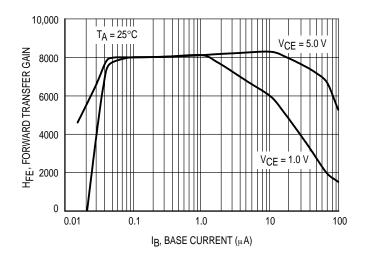


Figure 5. Non–Saturated and Saturated HFE versus Base Current

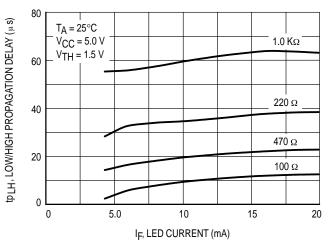


Figure 6. Low to High Propagation Delay versus Collector Load Resistance and LED Current

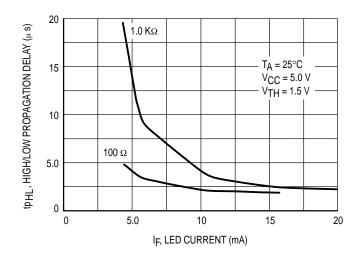
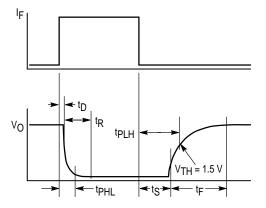


Figure 7. High to Low Propagation Delay versus Collector Load Resistance and LED Current



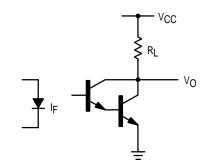
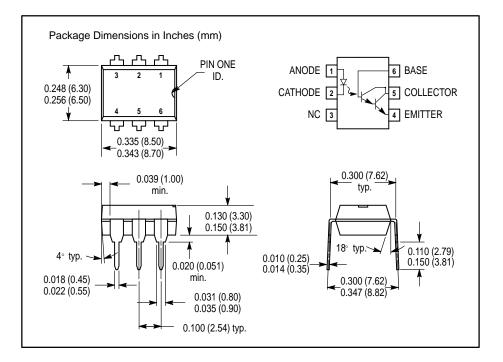


Figure 8. Switching Waveform

**Figure 9. Switching Schematic** 



Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and **(a)** are registered trademarks of Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

#### How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303–675–2140 or 1–800–441–2447 Mfax is a trademark of Motorola, Inc.

2447 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 81–3–3521–8315

Mfax™: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609 - US & Canada ONLY 1-800-774-184

INTERNET: http://www.mot.com/SPS/



 - TOUCHTONE 602–244–6609
 ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,

 - US & Canada ONLY 1–800–774–1848
 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, 6F Seibu-Butsuryu-Center,